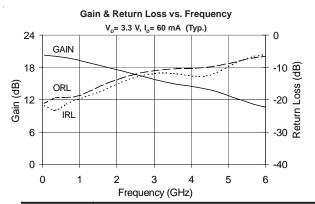


Product Description

The SGA-5489 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high $F_{\scriptscriptstyle T}$ and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.

The matte tin finish on Sirenza's lead-free package utilizes a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. This package is also manufactured with green molding compounds that contain no antimony trioxide nor halogenated fire retardants.



SGA-5489

SGA-5489Z



DC-4000 MHz, Cascadable SiGe HBT MMIC Amplifier



Product Features

- Now available in Lead Free, RoHS Compliant, & Green Packaging
- High Gain: 17.9 dB at 1950 MHz
- Cascadable 50 Ohm
- Operates From Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- · Wireless Data, Satellite

Symbol	Parameter	Units	Frequency	Min.	Тур.	Max.
G	Small Signal Gain	dB dB dB	850 MHz 1950 MHz 2400 MHz	17.7	19.7 17.9 17.1	21.7
P _{1dB}	Output Power at 1dB Compression	dBm dBm	850 MHz 1950 MHz		16.0 14.6	
OIP ₃	Output Third Order Intercept Point	dBm dBm	850 MHz 1950 MHz		30.8 27.4	
Bandwidth	Determined by Return Loss (>10dB)	MHz			4000	
IRL	Input Return Loss	dB	1950 MHz		15.4	
ORL	Output Return Loss	dB	1950 MHz		14.0	
NF	Noise Figure	dB	1950 MHz		2.4	
V _D	Device Operating Voltage	V		3.1	3.3	4.1
I _D	Device Operating Current	mA		54	60	66
R _{TH} , j-I	Thermal Resistance (junction to lead)	°C/W			97	
Tes	Test Conditions: $V_s = 8 \text{ V}$ $I_D = 60 \text{ mA Typ.}$ OIP ₃ Tone Spacing = 1 MHz, Pout per tone = 0 dBm $R_{BIAS} = 75 \text{ Ohms}$ $T_1 = 25^{\circ}\text{C}$ $Z_S = Z_1 = 50 \text{ Ohms}$					

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Phone: (800) SMI-MMIC

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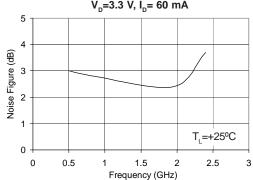


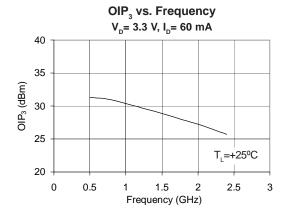
Typical RF Performance at Key Operating Frequencies

			Frequency (MHz)					
Symbol	Parameter	Unit	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	20.2	19.9	19.7	17.9	17.1	15.0
OIP ₃	Output Third Order Intercept Point	dBm		31.3	30.8	27.4	25.7	
P_{1dB}	Output Power at 1dB Compression	dBm		16.3	16.0	14.6	13.5	
IRL	Input Return Loss	dB	22.4	22.3	20.2	15.4	13.5	11.8
ORL	Output Return Loss	dB	20.5	19.4	19.1	14.0	12.4	10.4
S ₁₂	Reverse Isolation	dB	24.8	23.2	23.4	23.5	23.1	21.1
NF	Noise Figure	dB		3.0	2.8	2.4	3.7	

Test Conditions: $V_S = 8 \text{ V}$ $I_D = 60 \text{ mA Typ.}$ OIP_3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm $R_{BIAS} = 75 \text{ Ohms}$ $I_L = 25^{\circ}\text{C}$ $I_S = 25^{\circ$

Noise Figure vs. Frequency $V_p=3.3 \text{ V, } I_p=60 \text{ mA}$



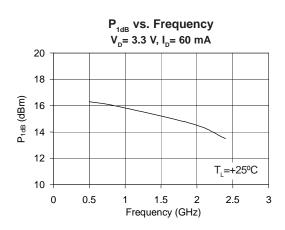


Absolute Maximum Ratings

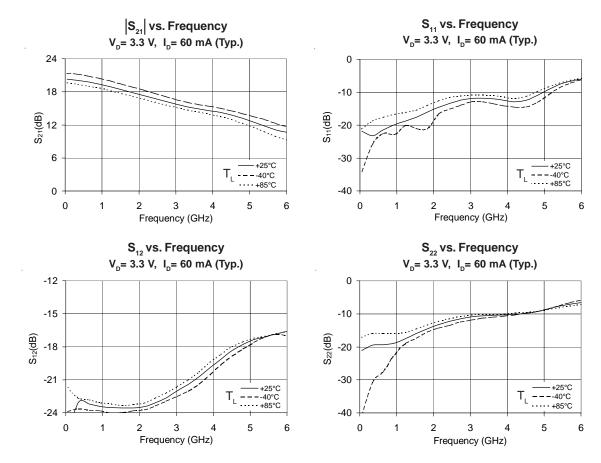
Parameter	Absolute Limit	
Max. Device Current (I _D)	120 mA	
Max. Device Voltage (V _D)	5 V	
Max. RF Input Power	+16 dBm	
Max. Junction Temp. (T _J)	+150°C	
Operating Temp. Range (T _L)	-40°C to +85°C	
Max. Storage Temp.	+150°C	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_{_D}V_{_D}<(T_{_J}-T_{_L})\ /\ R_{_{TH'}}\ j\text{-}I$



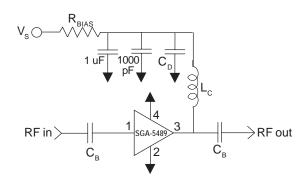


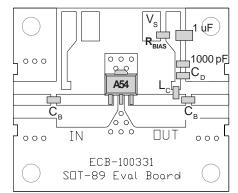


NOTE: Full S-parameter data available at www.sirenza.com

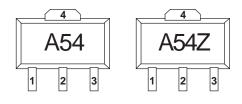


Basic Application Circuit





Part Identification Marking





See Application Note AN-075 for Package Outline Drawing

Application Circuit Element Values

Reference		Frequency (Mhz)					
Designator	500	850	1950	2400	3500		
C _B	220 pF	100 pF	68 pF	56 pF	39 pF		
C _D	100 pF	68 pF	22 pF	22 pF	15 pF		
L _c	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_{\rm p}$ =60mA $R_{\rm BIAS}$ =($V_{\rm s}$ - $V_{\rm p}$) / $I_{\rm p}$					
Supply Voltage(V _s)	6 V	8 V	10 V	12 V	
R _{BIAS} 43 Ω 75 Ω 110 Ω 150 Ω					
Note: R _{BIAS} provides DC bias stability over temperature.					

Mounting Instructions

- 1. Solder the copper pad on the backside of the device package to the ground plane.
- 2. Use a large ground pad area with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurement for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SGA-5489	13"	3000
SGA-5489Z	13"	3000

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